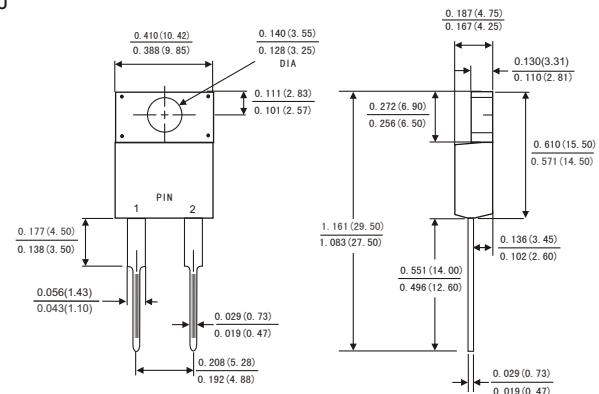


FEATURES

- Plastic package has Underwriters Laboratory Flammability Classification 94V-0
- Metal silicon junction ,majority carrier conduction
- Guard ring for overvoltage protection
- Low power loss ,high efficiency
- High current capability ,low forward voltage drop
- Single rectifier construction
- High surge capability
- For use in low voltage ,high frequency inverters, free wheeling ,and polarity protection applications
- High temperature soldering guaranteed:260°C/10 seconds, 0.25"(6.35mm)from case
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC



ITO-220AC



Dimensions in inches and (millimeters)

MECHANICAL DATA

- Case: JEDEC ITO-220AC molded plastic body
- Terminals: Lead solderable per MIL-STD-750,method 2026
- Polarity: As marked
- Mounting Position: Any
- Weight: 0.08ounce, 2.24 gram

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

(Ratings at 25°C ambient temperature unless otherwise specified ,Single phase ,half wave ,resistive or inductive load. For capacitive load, derate by 20%.)

	Symbols	SRF 820	SRF 830	SRF 840	SRF 850	SRF 860	SRF 880	SRF 8100	SRF 8150	SRF 8200	Units							
Maximum repetitive peak reverse voltage	V _{RRM}	20	30	40	50	60	80	100	150	200	Volts							
Maximum RMS voltage	V _{RMS}	14	21	28	35	42	56	70	105	140	Volts							
Maximum DC blocking voltage	V _{DC}	20	30	40	50	60	80	100	150	200	Volts							
Maximum average forward rectified current (see Fig.1)	I _(AV)	8.0								Amps								
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC method)	I _{FSM}	150.0								Amps								
Maximum instantaneous forward voltage at 8.0 A(Notes 1)	V _F	0. 60		0.75		0.85		0.90		0.95	Volts							
Maximum instantaneous reverse current at rated DC blocking voltage(Notes 1)	T _A =25°C T _A =125°C	I _R	0.2								mA							
			15		50													
Typical thermal resistance (Notes 2)	R _{θJC}	2.5								°C/W								
Operating junction temperature range	T _J	-65 to +150								°C								
Storage temperature range	T _{STG}	-65 to +150								°C								

Notes: 1.Pulse test: 300 μ s pulse width,1% duty cycle

2.Thermal resistance from junction to case



SRF820 THRU SRF8200(SINGLE CHIP) RATINGS AND CHARACTERISTIC CURVES

FIG.1-FORWARD CURRENT DERATING CURVE

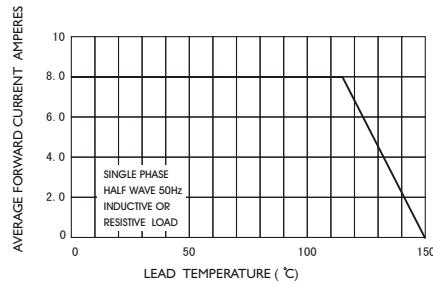


FIG.4-TYPICAL JUNCTION CAPACITANCE

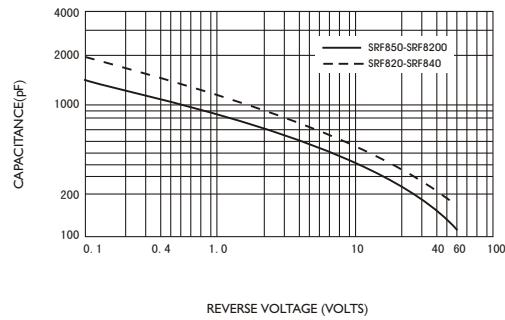


FIG.5-MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

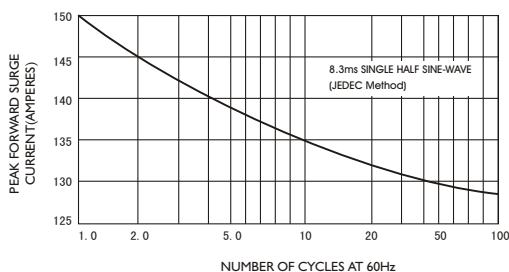


FIG.2-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

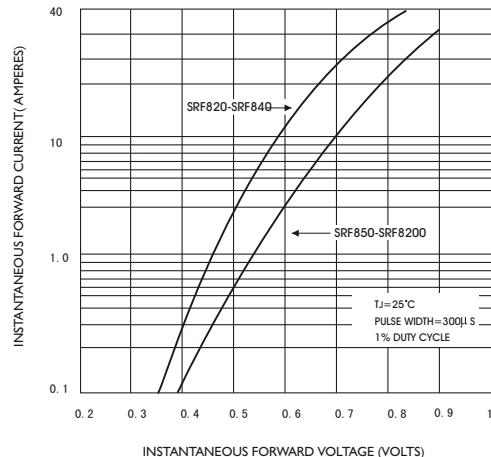


FIG.3-TYPICAL REVERSE CHARACTERISTICS

